

Features

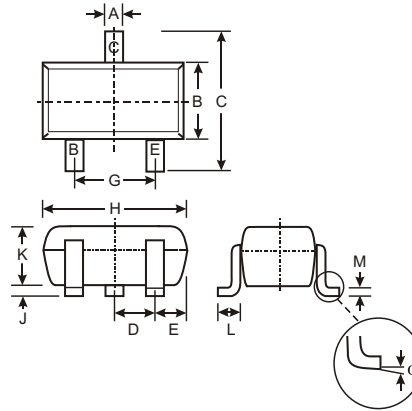
Ideally Suited for Automatic Insertion
 Epitaxial Planar Die Construction
 For Switching, AF Driver and Amplifier Applications
 Complementary PNP Types Available (BC807-xxW)
Lead Free By Design/RoHS Compliant (Note 1)
"Green" Device (Note 2)

Mechanical Data

Case: SOT-323
 Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
 Moisture Sensitivity: Level 1 per J-STD-020C
 Terminals: Finish – Matte Tin annealed over Alloy 42
 leadframe. Solderable per MIL-STD-202, Method 208
 Pin Connections: See Diagram

Marking:

P/N	Marking
BC817-16W	K6A
BC817-25W	K6B
BC817-40W	K6C



SOT-323		
Dim	Min	Max
A	0.25	0.40
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
E	0.30	0.40
G	1.20	1.40
H	1.80	2.20
J	0.0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.18
	0	8
All Dimensions in mm		

Ordering & Date Code Information: See Page 3

Approximate Weight: 0.006 grams

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	45	V
Emitter-Base Voltage	V _{EBO}	5.0	V
Collector Current	I _C	500	mA
Peak Collector Current	I _{CM}	1000	mA
Peak Emitter Current	I _{EM}	1000	mA
Power Dissipation at T _{SB} = 50°C (Note 3)	P _d	200	mW
Thermal Resistance, Junction to Ambient Air (Note 3)	R _{JA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic (Note 4)	Symbol	Min	Max	Unit	Test Condition
DC Current Gain	h _{FE}	100	250	—	V _{CE} = 1.0V, I _C = 100mA
Current Gain Group -16		160	400		V _{CE} = 1.0V, I _C = 300mA
-25		250	600		
-40		60	—		
Current Gain Group -16	h _{FE}	100	—	—	V _{CE} = 1.0V, I _C = 300mA
-25		100	—		
-40		170	—		
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	0.7	V	I _C = 500mA, I _B = 50mA
Base-Emitter Voltage	V _{BE}	—	1.2	V	V _{CE} = 1.0V, I _C = 300mA
Collector-Emitter Cutoff Current	I _{CES}	—	100 5.0	nA μA	V _{CE} = 45V V _{CE} = 25V, T _J = 150°C
Emitter-Base Cutoff Current	I _{EBO}	—	100	nA	V _{EB} = 4.0V
Gain Bandwidth Product	f _T	100	—	MHz	V _{CE} = 5.0V, I _C = 10mA, f = 50MHz
Collector-Base Capacitance	C _{CBO}	—	12	pF	V _{CB} = 10V, f = 1.0MHz

- Notes:
1. No purposefully added lead.
 2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 3. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
 4. Short duration pulse test used to minimize self-heating effect.

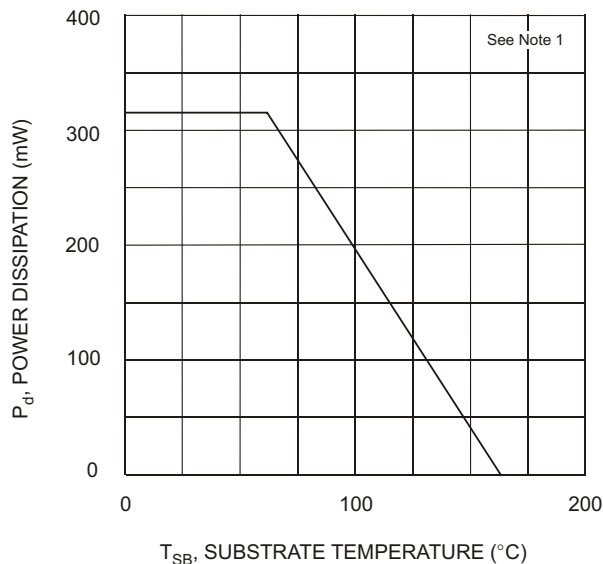


Fig. 1, Power Derating Curve

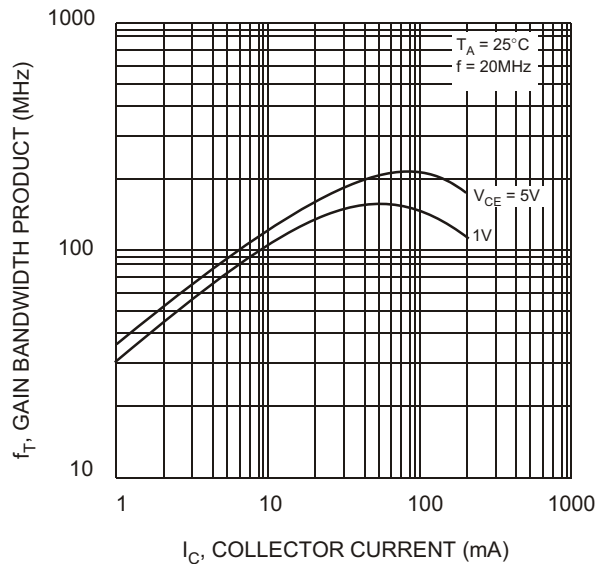


Fig. 2, Gain-Bandwidth Product vs Collector Current

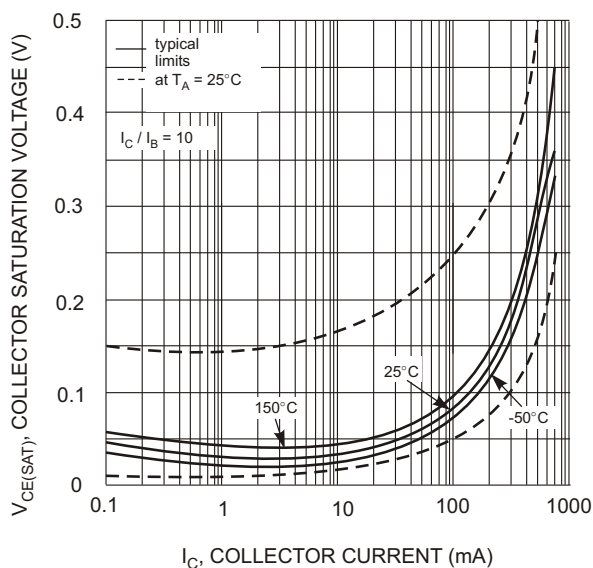


Fig. 3, Collector Sat. Voltage vs Collector Current

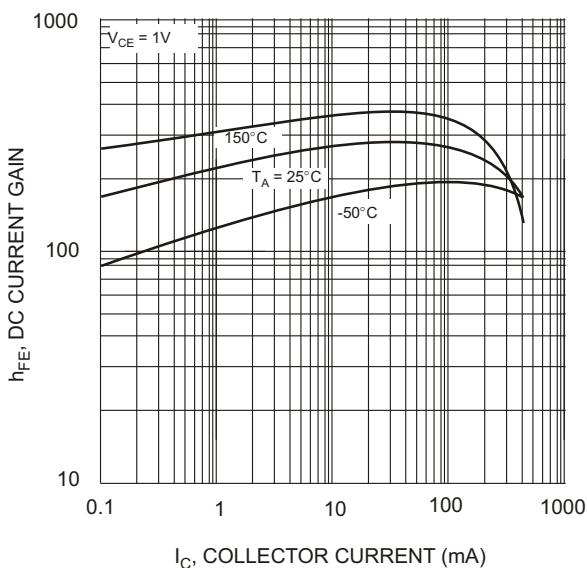


Fig. 4, DC Current Gain vs Collector Current

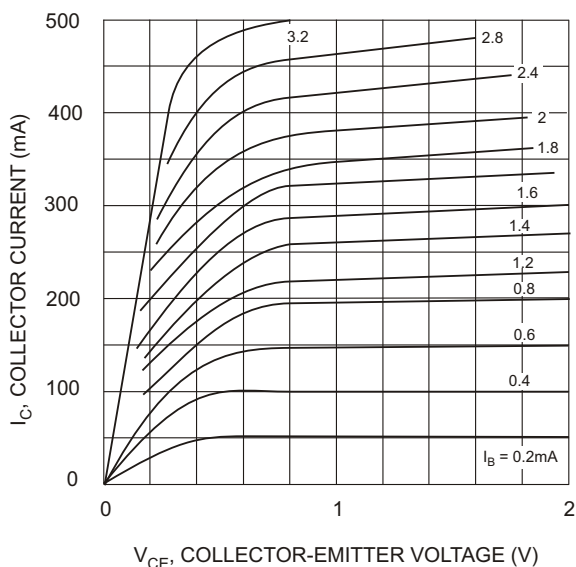


Fig. 5, Typical Emitter-Collector Characteristics

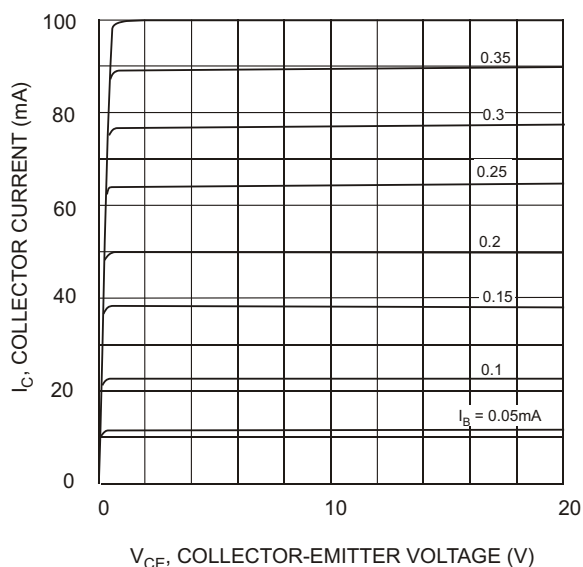


Fig. 6, Typical Emitter-Collector Characteristics

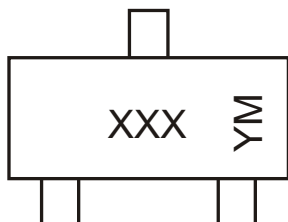
Ordering Information (Note 5)

Device*	Packaging	Shipping
BC817-xxW-7	SOT-323	3000/Tape & Reel

Notes: 5. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

* xx = gain group, e.g. BC817-16W-7.

Marking Information



XXX = Product Type Marking Code (See Page 1), e.g. K6A = BC817-16

YM = Date Code Marking

Y = Year ex: S = 2005

M = Month ex: 9 = September

Date Code Key

Year	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	R	S	T	U	V	W	X	Y	Z

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9